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Serial No. 10/039,290	Filing Date  January 4, 2002	Examiner	Group Art Unit 2877			
Invention: SUBMIGRON THERMAL IMAGING METHOD AND ENHANCED RESOLUTION (SUPER-RESOLVED)  ACCOURSED IMAGING FOR THERMAL INSPECTION OF INTEGRATED CIRCUITS  MAR 1 9 2002						
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CERTIFICATE OF I	Docket No. UC01-161-2					
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j	NEORMATION DISCLOSURE CITATION (Use several sheets if necessary)	Applicant(s) ALI SHAKOURI ET AL.				
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	MAR 1 9 2002 🐇	JANUARY 4, 2002	9855 2627			
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